

Form PTO-1449

INFORMATION DISCLOSURE CITATION
IN AN APPLICATION

(Use several sheets if necessary)

DocId Number (Sequence)

INT-03-014

Application Number

10/827,061

Applicant

Thomas Aisenbrey

Filing Date

04/19/04

Group Art Unit

2821

EX: CTRAM

U. S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	NUMO DATE IF APPROPRIATE
CT	61113438	29/00	Unami et al.	310	366	8/20/98
CT	4267480	5/12/81	Kanematsu et al.	310	366	5/23/79
CT	4786837	11/22/88	Kalnin et al.	310	364	5/5/87
CT	6664863	12/16/03	Okamoto et al.	331	117 R	7/24/00
CT	6268778	7/31/01	Mucke et al.	331	117 R	5/3/99

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
CT GB 2	377449A	1/15/03	United Kingdom	co8K	3/08		

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

CT -	Cleland et al., "Fabrication of high frequency nanometer scale mechanical resonators from bulk Si crystals", Applied Physics Letter 69(18), 28 Oct. 1996, pp. 2653-2655.
CT	

EXAMINER

/Chuc Tran/

DATE CONSIDERED

08/17/2006

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.